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### Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

### Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

#### Details

Product Status	Obsolete
Core Processor	ARM1136JF-S
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	532MHz
Co-Processors/DSP	Multimedia; GPU, IPU, MPEG-4, VFP
RAM Controllers	DDR
Graphics Acceleration	Yes
Display & Interface Controllers	Keyboard, Keypad, LCD
Ethernet	-
SATA	-
USB	USB 2.0 (3)
Voltage - I/O	1.8V, 2.0V, 2.5V, 2.7V, 3.0V
Operating Temperature	0°C ~ 70°C (TA)
Security Features	Random Number Generator, RTIC, Secure Fusebox, Secure JTAG, Secure Memory
Package / Case	473-LFBGA
Supplier Device Package	473-LFBGA (19x19)
Purchase URL	<a href="https://www.e-xfl.com/pro/item?MUrl=&amp;PartUrl=mcimx31lvmn5c">https://www.e-xfl.com/pro/item?MUrl=&amp;PartUrl=mcimx31lvmn5c</a>

## 2.2 Module Inventory

Table 3 shows an alphabetical listing of the modules in the multimedia applications processor. For extended descriptions of the modules, see the reference manual. A cross-reference is provided to the electrical specifications and timing information for each module with external signal connections.

**Table 3. Digital and Analog Modules**

Block Mnemonic	Block Name	Functional Grouping	Brief Description	Section/ Page
1-Wire®	1-Wire Interface	Connectivity Peripheral	The 1-Wire module provides bi-directional communication between the ARM11 core and external 1-Wire devices.	<a href="#">4.3.4/26</a>
ATA	Advanced Technology (AT) Attachment	Connectivity Peripheral	The ATA block is an AT attachment host interface. It is designed to interface with IDE hard disc drives and ATAPI optical disc drives.	<a href="#">4.3.5/27</a>
AUDMUX	Digital Audio Multiplexer	Multimedia Peripheral	The AUDMUX interconnections allow multiple, simultaneous audio/voice/data flows between the ports in point-to-point or point-to-multipoint configurations.	<a href="#">4.3.6/36</a>
CAMP	Clock Amplifier Module	Clock	The CAMP converts a square wave/sinusoidal input into a rail-to-rail square wave. The output of CAMP feeds the predivider.	<a href="#">4.3.3/25</a>
CCM	Clock Control Module	Clock	The CCM provides clock, reset, and power management control for the MCIMX31.	—
CSPI	Configurable Serial Peripheral Interface (x 3)	Connectivity Peripheral	The CSPI is equipped with data FIFOs and is a master/slave configurable serial peripheral interface module, capable of interfacing to both SPI master and slave devices.	<a href="#">4.3.7/36</a>
DPLL	Digital Phase Lock Loop	Clock	The DPLLs produce high-frequency on-chip clocks with low frequency and phase jitters. <b>Note:</b> External clock sources provide the reference frequencies.	<a href="#">4.3.8/37</a>
ECT	Embedded Cross Trigger	Debug	The ECT is composed of three CTIs (Cross Trigger Interface) and one CTM (Cross Trigger Matrix—key in the multi-core and multi-peripheral debug strategy.	—
EMI	External Memory Interface	Memory Interface (EMI)	The EMI includes <ul style="list-style-type: none"> <li>• Multi-Master Memory Interface (M3IF)</li> <li>• Enhanced SDRAM Controller (ESDCTL)</li> <li>• NAND Flash Controller (NFC)</li> <li>• Wireless External Interface Module (WEIM)</li> </ul>	— <a href="#">4.3.9.3/46</a> , <a href="#">4.3.9.1/38</a> , <a href="#">4.3.9.2/41</a>
EPIT	Enhanced Periodic Interrupt Timer	Timer Peripheral	The EPIT is a 32-bit “set and forget” timer which starts counting after the EPIT is enabled by software. It is capable of providing precise interrupts at regular intervals with minimal processor intervention.	—
ETM	Embedded Trace Macrocell	Debug/Trace	The ETM (from ARM, Ltd.) supports real-time instruction and data tracing by way of ETM auxiliary I/O port.	<a href="#">4.3.10/54</a>
FIR	Fast InfraRed Interface	Connectivity Peripheral	This FIR is capable of establishing a 0.576 Mbit/s, 1.152 Mbit/s or 4 Mbit/s half duplex link via a LED and IR detector. It supports 0.576 Mbit/s, 1.152 Mbit/s medium infrared (MIR) physical layer protocol and 4Mbit/s fast infrared (FIR) physical layer protocol defined by IrDA, Rev. 1.4.	<a href="#">4.3.11/55</a>

**Table 3. Digital and Analog Modules (continued)**

Block Mnemonic	Block Name	Functional Grouping	Brief Description	Section/ Page
SCC	Security Controller Module	Security	The SCC is a hardware component composed of two blocks—the Secure RAM module, and the Security Monitor. The Secure RAM provides a way of securely storing sensitive information.	—
SDHC	Secured Digital Host Controller	Connectivity Peripheral	The SDHC controls the MMC (MultiMediaCard), SD (Secure Digital) memory, and I/O cards by sending commands to cards and performing data accesses to and from the cards.	<a href="#">4.3.19/89</a>
SDMA	Smart Direct Memory Access	System Control Peripheral	The SDMA controller maximizes the system's performance by relieving the ARM core of the task of bulk data transfer from memory to memory or between memory and on-chip peripherals.	—
SIM	Subscriber Identification Module	Connectivity Peripheral	The SIM interfaces to an external Subscriber Identification Card. It is an asynchronous serial interface adapted for Smart Card communication for e-commerce applications.	<a href="#">4.3.20/90</a>
SJC	Secure JTAG Controller	Debug	The SJC provides debug and test control with maximum security and provides a flexible architecture for future derivatives or future multi-cores architecture.	<a href="#">4.3.21/94</a>
SSI	Synchronous Serial Interface	Multimedia Peripheral	The SSI is a full-duplex, serial port that allows the device to communicate with a variety of serial devices, such as standard codecs, Digital Signal Processors (DSPs), microprocessors, peripherals, and popular industry audio codecs that implement the inter-IC sound bus standard (I2S) and Intel AC97 standard.	<a href="#">4.3.22/96</a>
UART	Universal Asynchronous Receiver/Transmitter	Connectivity Peripheral	The UART provides serial communication capability with external devices through an RS-232 cable or through use of external circuitry that converts infrared signals to electrical signals (for reception) or transforms electrical signals to signals that drive an infrared LED (for transmission) to provide low speed IrDA compatibility.	—
USB	Universal Serial Bus—2 Host Controllers and 1 OTG (On-The-Go)	Connectivity Peripherals	<ul style="list-style-type: none"> <li>• USB Host 1 is designed to support transceiverless connection to the on-board peripherals in Low Speed and Full Speed mode, and connection to the ULPI (UTMI+ Low-Pin Count) and Legacy Full Speed transceivers.</li> <li>• USB Host 2 is designed to support transceiverless connection to the Cellular Modem Baseband Processor.</li> <li>• The USB-OTG controller offers HS/FS/LS capabilities in Host mode and HS/FS in device mode. In Host mode, the controller supports direct connection of a FS/LS device (without external hub). In device (bypass) mode, the OTG port functions as gateway between the Host 1 Port and the OTG transceiver.</li> </ul>	<a href="#">4.3.23/104</a>
WDOG	Watchdog Timer Module	Timer Peripheral	The WDOG module protects against system failures by providing a method for the system to recover from unexpected events or programming errors.	—

**Table 11. Fusebox Supply Current Parameters**

Ref. Num	Description	Symbol	Minimum	Typical	Maximum	Units
1	eFuse Program Current. <sup>1</sup> Current to program one eFuse bit: efuse_pgm = 3.0 V	$I_{\text{program}}$	—	35	60	mA
2	eFuse Read Current <sup>2</sup> Current to read an 8-bit eFuse word vdd_fusebox = 1.875 V	$I_{\text{read}}$	—	5	8	mA

<sup>1</sup> The current  $I_{\text{program}}$  is during program time ( $t_{\text{program}}$ ).

<sup>2</sup> The current  $I_{\text{read}}$  is present for approximately 50 ns of the read access to the 8-bit word, and only applies to Silicon Rev. 1.2 and previous.

### 4.1.1 Supply Current Specifications

Table 12 shows the core current consumption for 0°C to 70°C for Silicon Revision 1.2 and previous for the MCIMX31.

**Table 12. Current Consumption for 0°C to 70°C<sup>1, 2</sup> for Silicon Revision 1.2 and Previous**

Mode	Conditions	QVCC (Peripheral)		QVCC1 (ARM)		QVCC4 (L2)		FVCC + MVCC + SVCC + UVCC (PLL)		Unit
		Typ	Max	Typ	Max	Typ	Max	Typ	Max	
State Retention	<ul style="list-style-type: none"> <li>• QVCC and QVCC1 = 0.95 V</li> <li>• L2 caches are power gated (QVCC4 = 0 V)</li> <li>• All PLLs are off, VCC = 1.4 V</li> <li>• ARM is in well bias</li> <li>• FPM is off</li> <li>• 32 kHz input is on</li> <li>• CKIH input is off</li> <li>• CAMP is off</li> <li>• TCK input is off</li> <li>• All modules are off</li> <li>• No external resistive loads</li> <li>• RNGA oscillator is off</li> </ul>	0.80	—	0.50	—	—	—	0.04	—	mA
Wait	<ul style="list-style-type: none"> <li>• QVCC, QVCC1, and QVCC4 = 1.22 V</li> <li>• ARM is in wait for interrupt mode</li> <li>• MAX is active</li> <li>• L2 cache is stopped but powered</li> <li>• MCU PLL is on (532 MHz), VCC = 1.4 V</li> <li>• USB PLL and SPLL are off, VCC = 1.4 V</li> <li>• FPM is on</li> <li>• CKIH input is on</li> <li>• CAMP is on</li> <li>• 32 kHz input is on</li> <li>• All clocks are gated off</li> <li>• All modules are off (by programming CGR[2:0] registers)</li> <li>• RNGA oscillator is off</li> <li>• No external resistive loads</li> </ul>	6.00	—	3.00	—	0.04	—	3.50	—	mA

<sup>1</sup> Typical column: TA = 25°C

<sup>2</sup> Maximum column: TA = 70°C

## Electrical Characteristics

Table 14 shows the core current consumption for 0°C to 70°C for Silicon Revision 2.0 for the MCIMX31.

**Table 14. Current Consumption for 0°C to 70°C<sup>1, 2</sup> for Silicon Revision 2.0**

Mode	Conditions	QVCC (Peripheral)		QVCC1 (ARM)		QVCC4 (L2)		FVCC, +MVCC, +SVCC, +UVCC (PLL)		Unit
		Typ	Max	Typ	Max	Typ	Max	Typ	Max	
Deep Sleep	<ul style="list-style-type: none"> <li>QVCC = 0.95 V</li> <li>ARM and L2 caches are power gated (QVCC1 2= QVCC4 = 0 V)</li> <li>All PLLs are off, VCC = 1.4 V</li> <li>ARM is in well bias</li> <li>FPM is off</li> <li>32 kHz input is on</li> <li>CKIH input is off</li> <li>CAMP is off</li> <li>TCK input is off</li> <li>All modules are off</li> <li>No external resistive loads</li> <li>RNGA oscillator is off</li> </ul>	0.16	2.50	—	—	—	—	0.02	0.10	mA
State Retention	<ul style="list-style-type: none"> <li>QVCC and QVCC1 = 0.95 V</li> <li>L2 caches are power gated (QVCC4 = 0 V)</li> <li>All PLLs are off, VCC = 1.4 V</li> <li>ARM is in well bias</li> <li>FPM is off</li> <li>32 kHz input is on</li> <li>CKIH input is off</li> <li>CAMP is off</li> <li>TCK input is off</li> <li>All modules are off</li> <li>No external resistive loads</li> <li>RNGA oscillator is off</li> </ul>	0.16	2.50	0.07	1.60	—	—	0.02	0.10	mA
Wait	<ul style="list-style-type: none"> <li>QVCC, QVCC1, and QVCC4 = 1.22 V</li> <li>ARM is in wait for interrupt mode</li> <li>MAX is active</li> <li>L2 cache is stopped but powered</li> <li>MCU PLL is on (532 MHz), VCC = 1.4 V</li> <li>USB PLL and SPLL are off, VCC = 1.4 V</li> <li>FPM is on</li> <li>CKIH input is on</li> <li>CAMP is on</li> <li>32 kHz input is on</li> <li>All clocks are gated off</li> <li>All modules are off (by programming CGR[2:0] registers)</li> <li>RNGA oscillator is off</li> <li>No external resistive loads</li> </ul>	6.00	13.00	2.20	16.00	0.03	0.17	3.60	4.40	mA

<sup>1</sup> Typical column: TA = 25°C

<sup>2</sup> Maximum column: TA = 70°C

## 4.2 Supply Power-Up/Power-Down Requirements and Restrictions

Any MCIMX31 board design must comply with the power-up and power-down sequence guidelines as described in this section to guarantee reliable operation of the device. Any deviation from these sequences may result in any or all of the following situations:

- Cause excessive current during power up phase
- Prevent the device from booting
- Cause irreversible damage to the MCIMX31 (worst-case scenario)

### 4.2.1 Powering Up

The Power On Reset ( $\overline{\text{POR}}$ ) pin must be kept asserted (low) throughout the power up sequence. Power up logic must guarantee that all power sources reach their target values prior to the release (de-assertion) of  $\overline{\text{POR}}$ . [Figure 2](#) shows the power-up sequence for silicon Revisions 1.2 and previous. [Figure 3](#) and [Figure 4](#) show the power-up sequence for silicon Revision 2.0.

#### NOTE

Stages need to be performed in the order shown; however, *within* each stage, supplies can be powered up in any order. For example, supplies IOQVDD, NVCC1, and NVCC3 through NVCC10 do not need to be powered up in the order shown.

#### CAUTION

NVCC6 and NVCC9 must be at the same voltage potential. These supplies are connected together on-chip to optimize ESD damage immunity.

### 4.3.4 1-Wire Electrical Specifications

Figure 7 depicts the RPP timing, and Table 21 lists the RPP timing parameters.

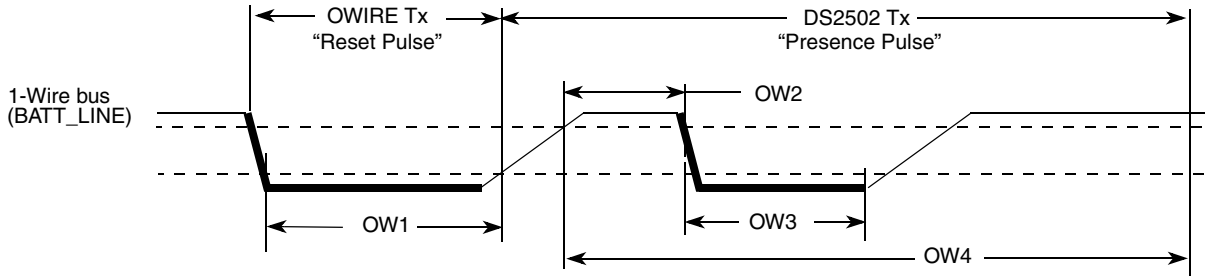


Figure 7. Reset and Presence Pulses (RPP) Timing Diagram

Table 21. RPP Sequence Delay Comparisons Timing Parameters

ID	Parameters	Symbol	Min	Typ	Max	Units
OW1	Reset Time Low	$t_{RSTL}$	480	511	—	$\mu s$
OW2	Presence Detect High	$t_{PDH}$	15	—	60	$\mu s$
OW3	Presence Detect Low	$t_{PDL}$	60	—	240	$\mu s$
OW4	Reset Time High	$t_{RSTH}$	480	512	—	$\mu s$

Figure 8 depicts Write 0 Sequence timing, and Table 22 lists the timing parameters.

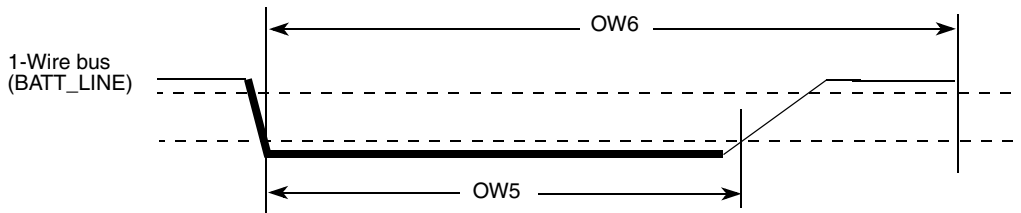


Figure 8. Write 0 Sequence Timing Diagram

Table 22. WR0 Sequence Timing Parameters

ID	Parameter	Symbol	Min	Typ	Max	Units
OW5	Write 0 Low Time	$t_{WR0\_low}$	60	100	120	$\mu s$
OW6	Transmission Time Slot	$t_{SLOT}$	OW5	117	120	$\mu s$

Figure 9 depicts Write 1 Sequence timing, Figure 10 depicts the Read Sequence timing, and Table 23 lists the timing parameters.



### 4.3.5.2 PIO Mode Timing

Figure 11 shows timing for PIO read, and Table 25 lists the timing parameters for PIO read.

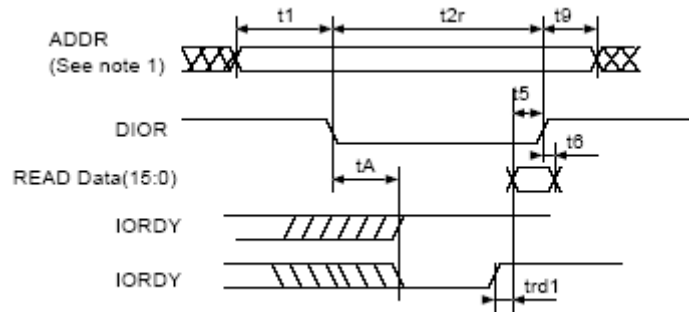


Figure 11. PIO Read Timing Diagram

Table 25. PIO Read Timing Parameters

ATA Parameter	Parameter from Figure 11	Value	Controlling Variable
t1	t1	$t_1 \text{ (min)} = \text{time\_1} * T - (\text{tskew1} + \text{tskew2} + \text{tskew5})$	time_1
t2	t2r	$t_2 \text{ min)} = \text{time\_2r} * T - (\text{tskew1} + \text{tskew2} + \text{tskew5})$	time_2r
t9	t9	$t_9 \text{ (min)} = \text{time\_9} * T - (\text{tskew1} + \text{tskew2} + \text{tskew6})$	time_3
t5	t5	$t_5 \text{ (min)} = t_{co} + t_{su} + t_{buf} + t_{buf} + t_{cable1} + t_{cable2}$	If not met, increase time_2
t6	t6	0	—
tA	tA	$t_A \text{ (min)} = (1.5 + \text{time\_ax}) * T - (t_{co} + t_{sui} + t_{cable2} + t_{cable2} + 2 * t_{buf})$	time_ax
trd	trd1	$trd1 \text{ (max)} = (-trd) + (\text{tskew3} + \text{tskew4})$ $trd1 \text{ (min)} = (\text{time\_pio\_rdx} - 0.5) * T - (t_{su} + t_{hi})$ $(\text{time\_pio\_rdx} - 0.5) * T > t_{su} + t_{hi} + \text{tskew3} + \text{tskew4}$	time_pio_rdx
t0	—	$t_0 \text{ (min)} = (\text{time\_1} + \text{time\_2} + \text{time\_9}) * T$	time_1, time_2r, time_9

Figure 12 shows timing for PIO write, and Table 26 lists the timing parameters for PIO write.

### 4.3.5.3 UDMA In Timing

Figure 15 shows timing when the UDMA in transfer starts, Figure 16 shows timing when the UDMA in host terminates transfer, Figure 17 shows timing when the UDMA in device terminates transfer, and Table 28 lists the timing parameters for UDMA in burst.

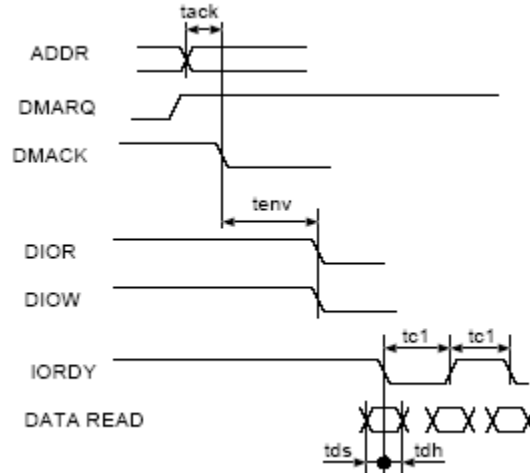


Figure 15. UDMA In Transfer Starts Timing Diagram

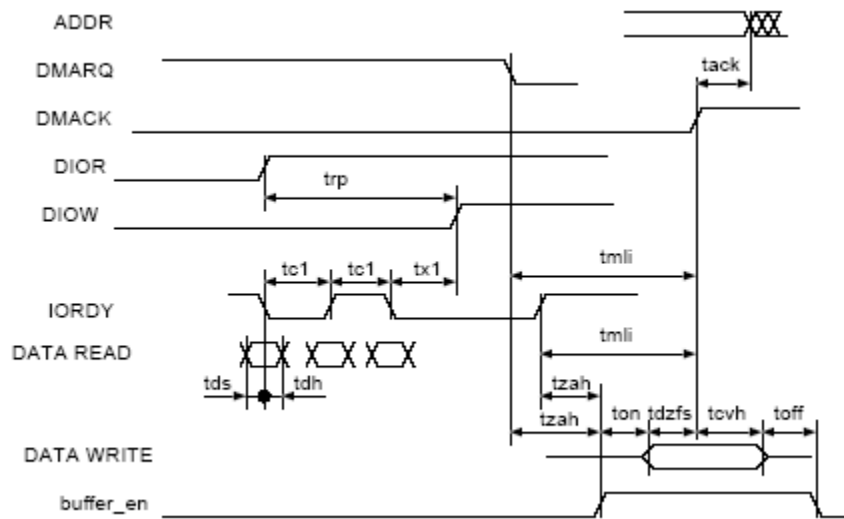


Figure 16. UDMA In Host Terminates Transfer Timing Diagram

### 4.3.6 AUDMUX Electrical Specifications

The AUDMUX provides a programmable interconnect logic for voice, audio and data routing between internal serial interfaces (SSI) and external serial interfaces (audio and voice codecs). The AC timing of AUDMUX external pins is hence governed by the SSI module. Please refer to their respective electrical specifications.

### 4.3.7 CSPI Electrical Specifications

This section describes the electrical information of the CSPI.

#### 4.3.7.1 CSPI Timing

Figure 21 and Figure 22 depict the master mode and slave mode timings of CSPI, and Table 30 lists the timing parameters.

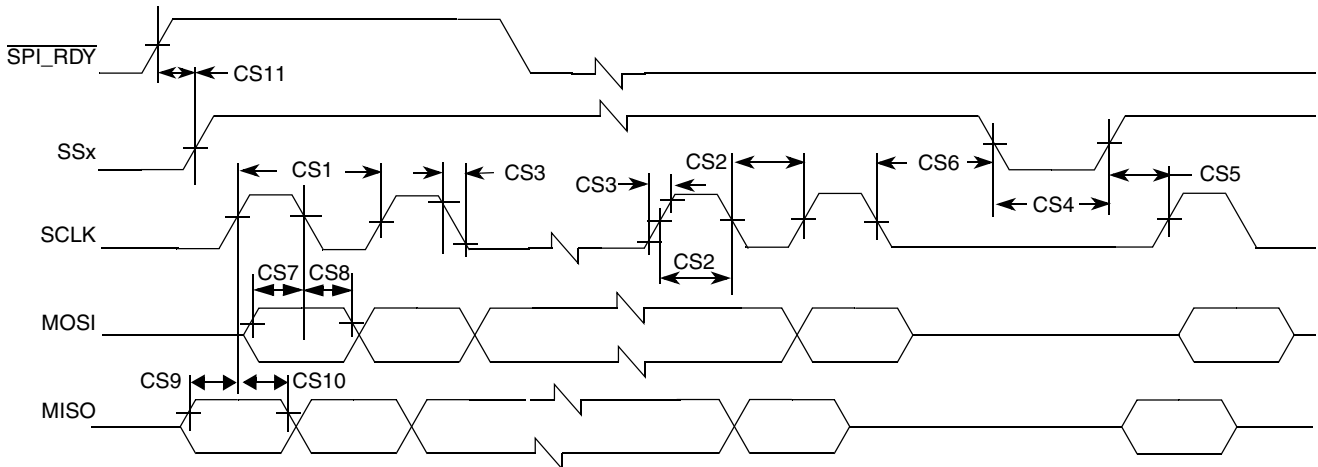


Figure 21. CSPI Master Mode Timing Diagram

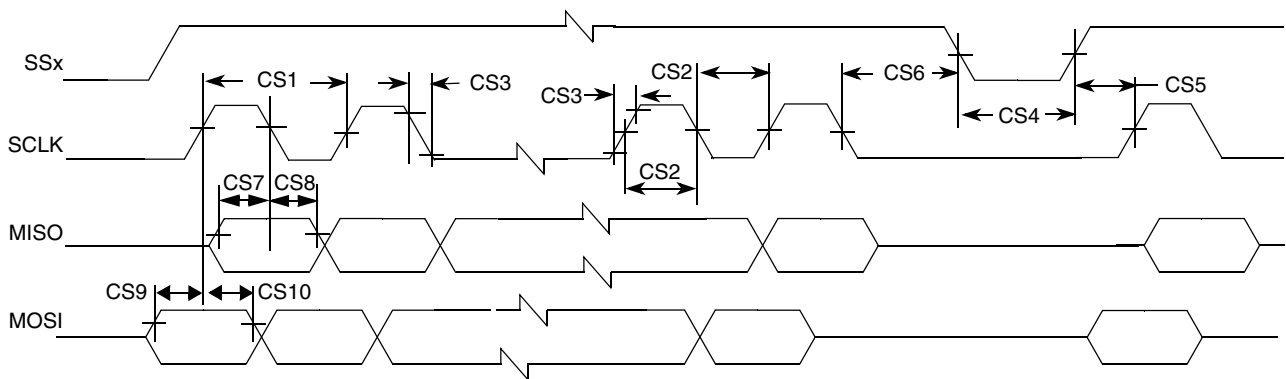
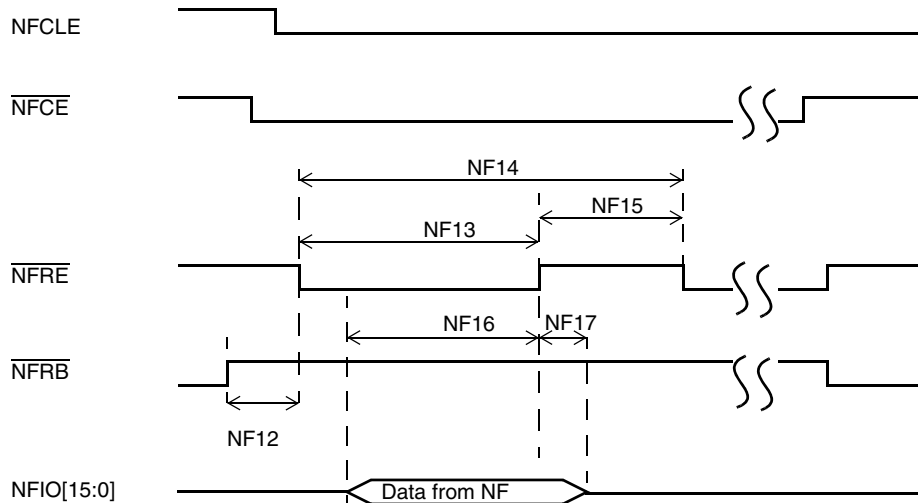


Figure 22. CSPI Slave Mode Timing Diagram

## Electrical Characteristics



**Figure 26. Read Data Latch Cycle Timing Diagram**

**Table 32. NFC Timing Parameters<sup>1</sup>**

ID	Parameter	Symbol	Timing T = NFC Clock Cycle <sup>2</sup>		Example Timing for NFC Clock ≈ 33 MHz T = 30 ns		Unit
			Min	Max	Min	Max	
NF1	NFCLE Setup Time	tCLS	T-1.0 ns	—	29	—	ns
NF2	NFCLE Hold Time	tCLH	T-2.0 ns	—	28	—	ns
NF3	$\overline{\text{NFCE}}$ Setup Time	tCS	T-1.0 ns	—	29	—	ns
NF4	$\overline{\text{NFCE}}$ Hold Time	tCH	T-2.0 ns	—	28	—	ns
NF5	$\overline{\text{NF\_WP}}$ Pulse Width	tWP	T-1.5 ns		28.5		ns
NF6	NFALE Setup Time	tALS	T	—	30	—	ns
NF7	NFALE Hold Time	tALH	T-3.0 ns	—	27	—	ns
NF8	Data Setup Time	tDS	T	—	30	—	ns
NF9	Data Hold Time	tDH	T-5.0 ns	—	25	—	ns
NF10	Write Cycle Time	tWC	2T		60		ns
NF11	$\overline{\text{NFW E}}$ Hold Time	tWH	T-2.5 ns		27.5		ns
NF12	Ready to $\overline{\text{NFRE}}$ Low	tRR	6T	—	180	—	ns
NF13	$\overline{\text{NFRE}}$ Pulse Width	tRP	1.5T	—	45	—	ns
NF14	READ Cycle Time	tRC	2T	—	60	—	ns
NF15	$\overline{\text{NFRE}}$ High Hold Time	tREH	0.5T-2.5 ns		12.5	—	ns
NF16	Data Setup on READ	tDSR	N/A		10	—	ns
NF17	Data Hold on READ	tDHR	N/A		0	—	ns

<sup>1</sup> The flash clock maximum frequency is 50 MHz.

<sup>2</sup> Subject to DPLL jitter specification on [Table 31, "DPLL Specifications,"](#) on page 37.

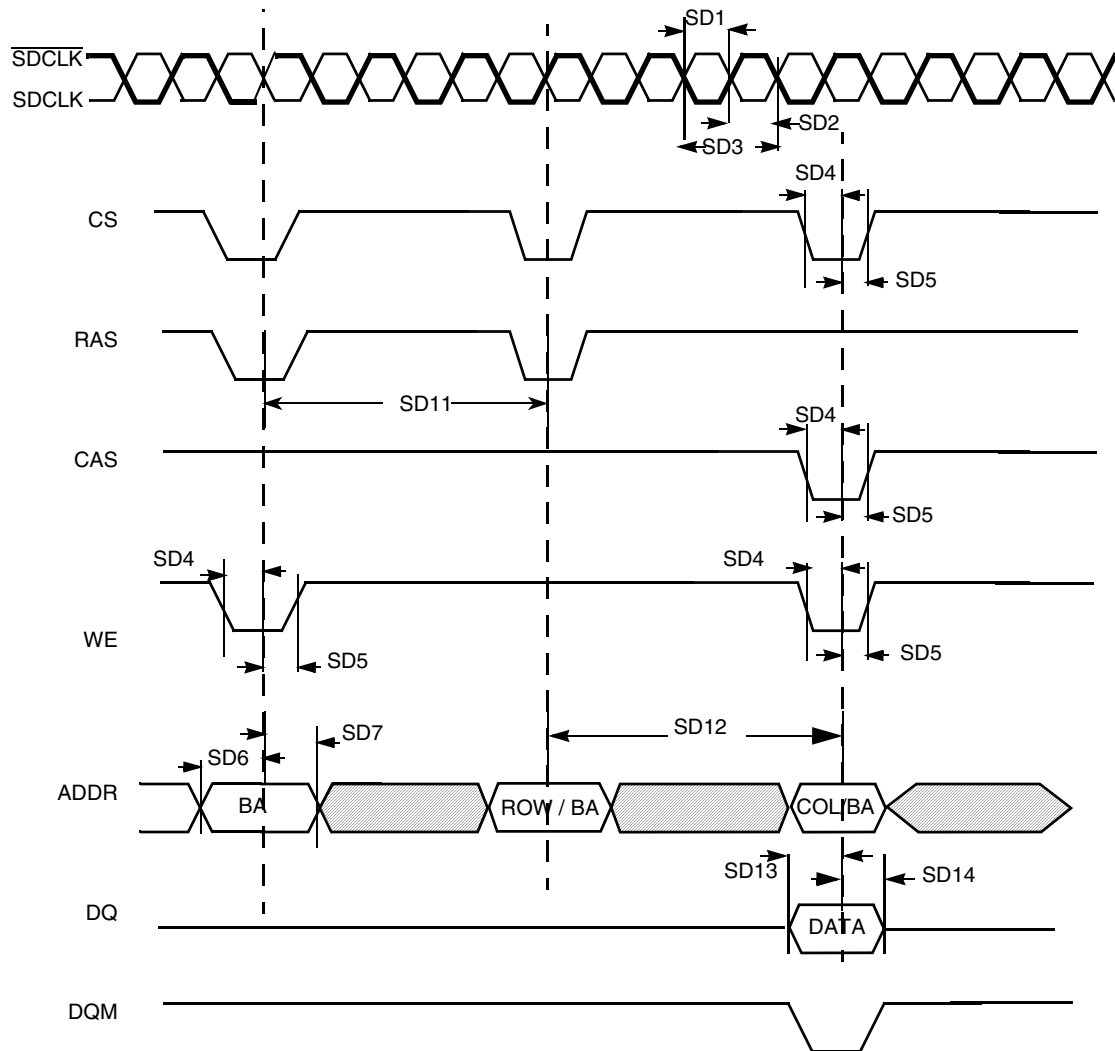


Figure 35. SDR SDRAM Write Cycle Timing Diagram

Table 35. SDR SDRAM Write Timing Parameters

ID	Parameter	Symbol	Min	Max	Unit
SD1	SDRAM clock high-level width	t <sub>CH</sub>	3.4	4.1	ns
SD2	SDRAM clock low-level width	t <sub>CL</sub>	3.4	4.1	ns
SD3	SDRAM clock cycle time	t <sub>CK</sub>	7.5	—	ns
SD4	CS, RAS, CAS, WE, DQM, CKE setup time	t <sub>CMS</sub>	2.0	—	ns
SD5	CS, RAS, CAS, WE, DQM, CKE hold time	t <sub>CMH</sub>	1.8	—	ns
SD6	Address setup time	t <sub>AS</sub>	2.0	—	ns
SD7	Address hold time	t <sub>AH</sub>	1.8	—	ns
SD11	Precharge cycle period <sup>1</sup>	t <sub>RP</sub>	1	4	clock
SD12	Active to read/write command delay <sup>1</sup>	t <sub>RCD</sub>	1	8	clock

## 4.3.14 IPU—Sensor Interfaces

### 4.3.14.1 Supported Camera Sensors

Table 44 lists the known supported camera sensors at the time of publication.

**Table 44. Supported Camera Sensors<sup>1</sup>**

Vendor	Model
Conexant	CX11646, CX20490 <sup>2</sup> , CX20450 <sup>2</sup>
Agilent	HDCCP-2010, ADCS-1021 <sup>2</sup> , ADCS-1021 <sup>2</sup>
Toshiba	TC90A70
ICMedia	ICM202A, ICM102 <sup>2</sup>
iMagic	IM8801
Transchip	TC5600, TC5600J, TC5640, TC5700, TC6000
Fujitsu	MB86S02A
Micron	MI-SOC-0133
Matsushita	MN39980
STMicro	W6411, W6500, W6501 <sup>2</sup> , W6600 <sup>2</sup> , W6552 <sup>2</sup> , STV0974 <sup>2</sup>
OmniVision	OV7620, OV6630
Sharp	LZ0P3714 (CCD)
Motorola	MC30300 (Python) <sup>2</sup> , SCM20014 <sup>2</sup> , SCM20114 <sup>2</sup> , SCM22114 <sup>2</sup> , SCM20027 <sup>2</sup>
National Semiconductor	LM9618 <sup>2</sup>

<sup>1</sup> Freescale Semiconductor does not recommend one supplier over another and in no way suggests that these are the only camera suppliers.

<sup>2</sup> These sensors not validated at time of publication.

### 4.3.14.2 Functional Description

There are three timing modes supported by the IPU.

#### 4.3.14.2.1 Pseudo BT.656 Video Mode

Smart camera sensors, which include imaging processing, usually support video mode transfer. They use an embedded timing syntax to replace the SENS<sub>B</sub>\_VSYNC and SENS<sub>B</sub>\_HSYNC signals. The timing syntax is defined by the BT.656 standard.

This operation mode follows the recommendations of ITU BT.656 specifications. The only control signal used is SENS<sub>B</sub>\_PIX\_CLK. Start-of-frame and active-line signals are embedded in the data stream. An active line starts with a SAV code and ends with a EAV code. In some cases, digital blanking is inserted in between EAV and SAV code. The CSI decodes and filters out the timing-coding from the data stream, thus recovering SENS<sub>B</sub>\_VSYNC and SENS<sub>B</sub>\_HSYNC signals for internal use.

**Table 49. Sharp Synchronous Display Interface Timing Parameters—Pixel Level**

ID	Parameter	Symbol	Value	Units
IP21	SPL rise time	Tsplr	$(BGXP - 1) * Tdpcp$	ns
IP22	CLS rise time	Tclsr	$CLS\_RISE\_DELAY * Tdpcp$	ns
IP23	CLS fall time	Tclsf	$CLS\_FALL\_DELAY * Tdpcp$	ns
IP24	CLS rise and PS fall time	Tpsf	$PS\_FALL\_DELAY * Tdpcp$	ns
IP25	PS rise time	Tpsr	$PS\_RISE\_DELAY * Tdpcp$	ns
IP26	REV toggle time	Trev	$REV\_TOGGLE\_DELAY * Tdpcp$	ns

#### 4.3.15.4 Synchronous Interface to Dual-Port Smart Displays

Functionality and electrical characteristics of the synchronous interface to dual-port smart displays are identical to parameters of the synchronous interface. See [Section 4.3.15.2.2, “Interface to Active Matrix TFT LCD Panels, Electrical Characteristics.”](#)

##### 4.3.15.4.1 Interface to a TV Encoder, Functional Description

The interface has an 8-bit data bus, transferring a single 8-bit value (Y/U/V) in each cycle. The bits D7–D0 of the value are mapped to bits LD17–LD10 of the data bus, respectively. [Figure 51](#) depicts the interface timing,

- The frequency of the clock DISPB\_D3\_CLK is 27 MHz (within 10%).
- The DISPB\_D3\_HSYNC, DISPB\_D3\_VSYNC and DISPB\_D3\_DRDY signals are active low.
- The transition to the next row is marked by the negative edge of the DISPB\_D3\_HSYNC signal. It remains low for a single clock cycle.
- The transition to the next field/frame is marked by the negative edge of the DISPB\_D3\_VSYNC signal. It remains low for at least one clock cycle.
  - At a transition to an odd field (of the next frame), the negative edges of DISPB\_D3\_VSYNC and DISPB\_D3\_HSYNC coincide.
  - At a transition to an even field (of the same frame), they do not coincide.
- The active intervals—during which data is transferred—are marked by the DISPB\_D3\_HSYNC signal being high.

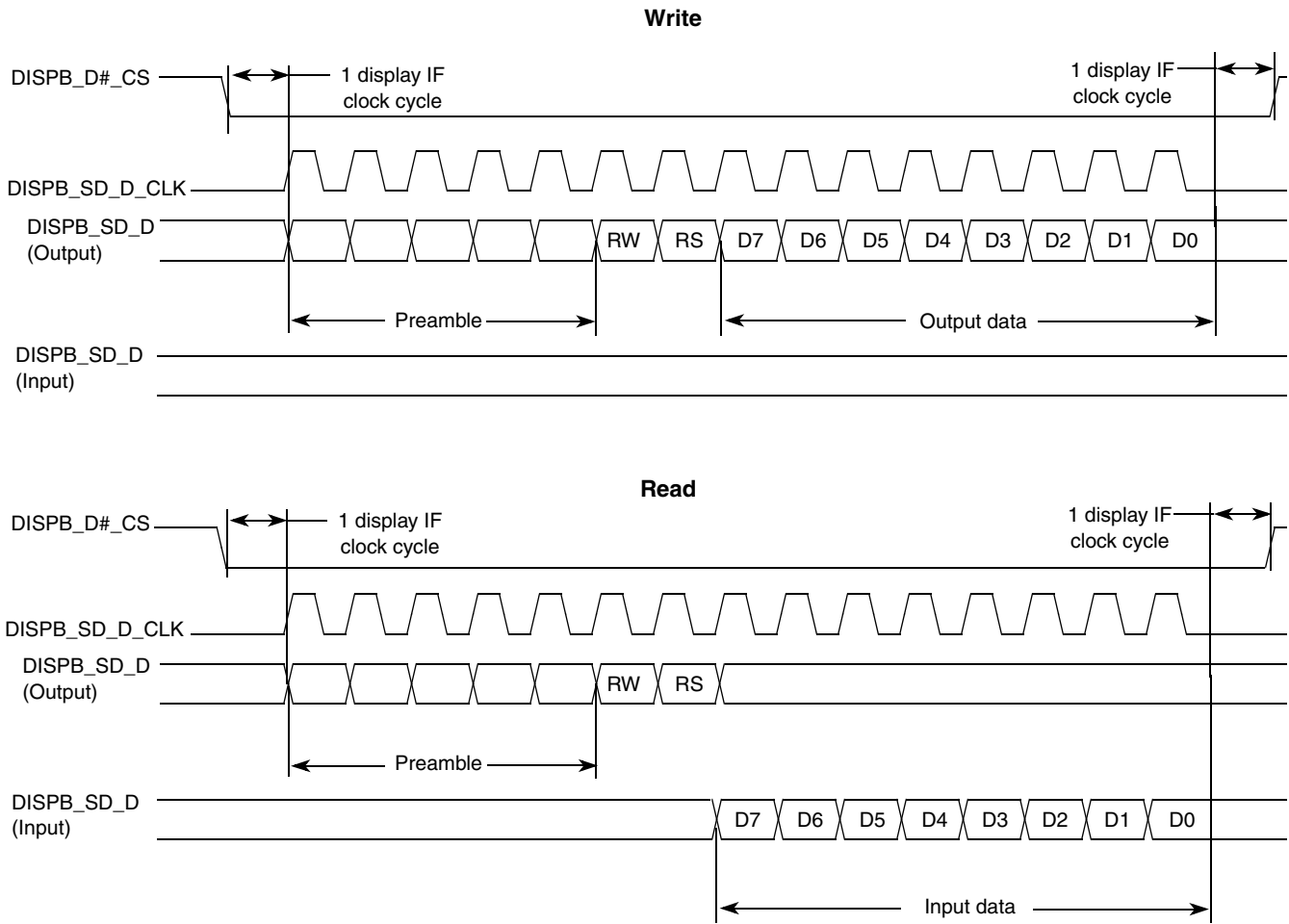


Figure 62. 4-Wire Serial Interface Timing Diagram

Figure 63 depicts timing of the 5-wire serial interface (Type 1). For this interface, a separate RS line is added. When a burst is transmitted within single active chip select interval, the RS can be changed at boundaries of words.



**Table 51. Asynchronous Serial Interface Timing Parameters—Access Level (continued)**

ID	Parameter	Symbol	Min.	Typ. <sup>1</sup>	Max.	Units
IP56	Controls setup time for write	Tdcsw	Tdicuw–1.5	Tdicuw	—	ns
IP57	Controls hold time for write	Tdchw	Tdicpw–Tdicdw–1.5	Tdicpw–Tdicdw	—	ns
IP58	Slave device data delay <sup>8</sup>	Tracc	0	—	Tdrp <sup>9</sup> –Tlbd <sup>10</sup> –Tdicur–1.5	ns
IP59	Slave device data hold time <sup>8</sup>	Troh	Tdrp–Tlbd–Tdicdr+1.5	—	Tdicpr–Tdicdr–1.5	ns
IP60	Write data setup time	Tds	Tdicdw–1.5	Tdicdw	—	ns
IP61	Write data hold time	Tdh	Tdicpw–Tdicdw–1.5	Tdicpw–Tdicdw	—	ns
IP62	Read period <sup>2</sup>	Tdicpr	Tdicpr–1.5	Tdicpr	Tdicpr+1.5	ns
IP63	Write period <sup>3</sup>	Tdicpw	Tdicpw–1.5	Tdicpw	Tdicpw+1.5	ns
IP64	Read down time <sup>4</sup>	Tdicdr	Tdicdr–1.5	Tdicdr	Tdicdr+1.5	ns
IP65	Read up time <sup>5</sup>	Tdicur	Tdicur–1.5	Tdicur	Tdicur+1.5	ns
IP66	Write down time <sup>6</sup>	Tdicdw	Tdicdw–1.5	Tdicdw	Tdicdw+1.5	ns
IP67	Write up time <sup>7</sup>	Tdicuw	Tdicuw–1.5	Tdicuw	Tdicuw+1.5	ns
IP68	Read time point <sup>9</sup>	Tdrp	Tdrp–1.5	Tdrp	Tdrp+1.5	ns

<sup>1</sup> The exact conditions have not been finalized, but will likely match the current customer requirement for their specific display. These conditions may be device specific.

<sup>2</sup> Display interface clock period value for read:

$$T_{dicpr} = T_{HSP\_CLK} \cdot \text{ceil} \left[ \frac{DISP\#\_IF\_CLK\_PER\_RD}{HSP\_CLK\_PERIOD} \right]$$

<sup>3</sup> Display interface clock period value for write:

$$T_{dicpw} = T_{HSP\_CLK} \cdot \text{ceil} \left[ \frac{DISP\#\_IF\_CLK\_PER\_WR}{HSP\_CLK\_PERIOD} \right]$$

<sup>4</sup> Display interface clock down time for read:

$$T_{dicdr} = \frac{1}{2} T_{HSP\_CLK} \cdot \text{ceil} \left[ \frac{2 \cdot DISP\#\_IF\_CLK\_DOWN\_RD}{HSP\_CLK\_PERIOD} \right]$$

<sup>5</sup> Display interface clock up time for read:

$$T_{dicur} = \frac{1}{2} T_{HSP\_CLK} \cdot \text{ceil} \left[ \frac{2 \cdot DISP\#\_IF\_CLK\_UP\_RD}{HSP\_CLK\_PERIOD} \right]$$

<sup>6</sup> Display interface clock down time for write:

$$T_{dicdw} = \frac{1}{2} T_{HSP\_CLK} \cdot \text{ceil} \left[ \frac{2 \cdot DISP\#\_IF\_CLK\_DOWN\_WR}{HSP\_CLK\_PERIOD} \right]$$

<sup>7</sup> Display interface clock up time for write:

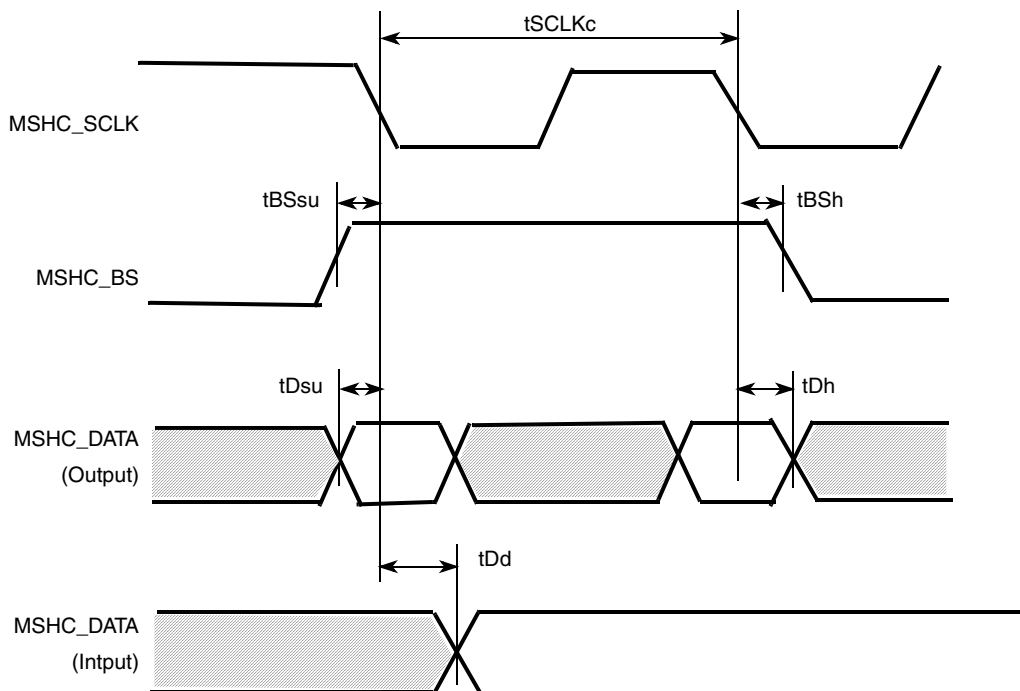
$$T_{dicuw} = \frac{1}{2} T_{HSP\_CLK} \cdot \text{ceil} \left[ \frac{2 \cdot DISP\#\_IF\_CLK\_UP\_WR}{HSP\_CLK\_PERIOD} \right]$$

<sup>8</sup> This parameter is a requirement to the display connected to the IPU.

<sup>9</sup> Data read point:

$$T_{drp} = T_{HSP\_CLK} \cdot \text{ceil} \left[ \frac{DISP\#\_READ\_EN}{HSP\_CLK\_PERIOD} \right]$$

<sup>10</sup> Loopback delay Tlbd is the cumulative propagation delay of read controls and read data. It includes an IPU output delay, a device-level output delay, board delays, a device-level input delay, an IPU input delay. This value is device specific.


**Figure 68. Transfer Operation Timing Diagram (Parallel)**
**NOTE**

The Memory Stick Host Controller is designed to meet the timing requirements per Sony's *Memory Stick Pro Format Specifications* document. Tables in this section details the specifications requirements for parallel and serial modes, and not the MCIMX31 timing.

**Table 52. Serial Interface Timing Parameters<sup>1</sup>**

Signal	Parameter	Symbol	Standards		Unit
			Min.	Max.	
MSHC_SCLK	Cycle	tSCLKc	50	—	ns
	H pulse length	tSCLKwh	15	—	ns
	L pulse length	tSCLKwl	15	—	ns
	Rise time	tSCLKr	—	10	ns
	Fall time	tSCLKf	—	10	ns
MSHC_BS	Setup time	tBSsu	5	—	ns
	Hold time	tBSsh	5	—	ns
MSHC_DATA	Setup time	tDsu	5	—	ns
	Hold time	tDh	5	—	ns
	Output delay time	tDd	—	15	ns

<sup>1</sup> Timing is guaranteed for NVCC from 2.7 through 3.1 V and up to a maximum overdrive NVCC of 3.3 V. See NVCC restrictions described in [Table 8, "Operating Ranges," on page 13.](#)

**Table 53. Parallel Interface Timing Parameters<sup>1</sup>**

Signal	Parameter	Symbol	Standards		Unit
			Min	Max	
MSHC_SCLK	Cycle	tSCLKc	25	—	ns
	H pulse length	tSCLKwh	5	—	ns
	L pulse length	tSCLKwl	5	—	ns
	Rise time	tSCLKr	—	10	ns
	Fall time	tSCLKf	—	10	ns
MSHC_BS	Setup time	tBSsu	8	—	ns
	Hold time	tBSH	1	—	ns
MSHC_DATA	Setup time	tDsu	8	—	ns
	Hold time	tDh	1	—	ns
	Output delay time	tDd	—	15	ns

<sup>1</sup> Timing is guaranteed for NVCC from 2.7 through 3.1 V and up to a maximum overdrive NVCC of 3.3 V. See NVCC restrictions described in [Table 8, "Operating Ranges,"](#) on page 13.

### 4.3.17 Personal Computer Memory Card International Association (PCMCIA)

[Figure 69](#) and [Figure 70](#) depict the timings pertaining to the PCMCIA module, each of which is an example of one clock of strobe set-up time and one clock of strobe hold time. [Table 54](#) lists the timing parameters.

### 4.3.20.3 Power Down Sequence

Power down sequence for SIM interface is as follows:

1. SIMPD port detects the removal of the SIM Card
2. RST goes Low
3. CLK goes Low
4. TX goes Low
5. VEN goes Low

Each of this steps is done in one CKIL period (usually 32 kHz). Power down can be started because of a SIM Card removal detection or launched by the processor. [Figure 76](#) and [Table 58](#) show the usual timing requirements for this sequence, with  $F_{ckil}$  = CKIL frequency value.

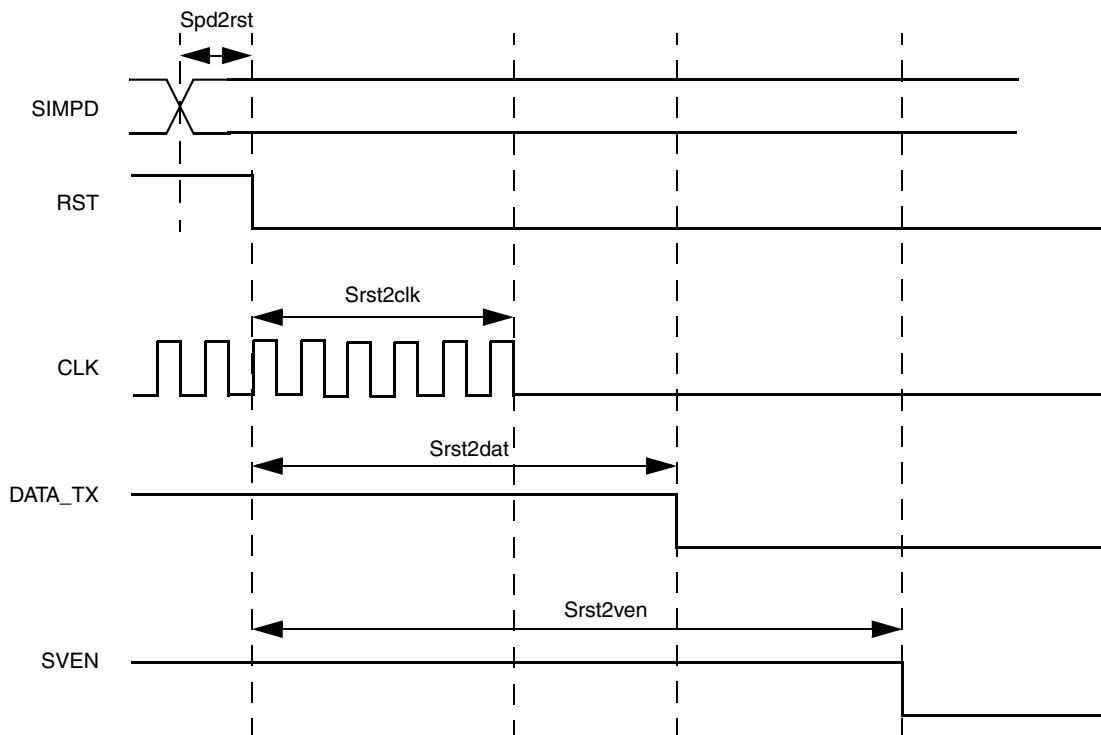


Figure 76. SmartCard Interface Power Down AC Timing

Table 58. Timing Requirements for Power Down Sequence

Num	Description	Symbol	Min	Max	Unit
1	SIM reset to SIM clock stop	$S_{rst2clk}$	$0.9 \cdot 1 / F_{CKIL}$	0.8	$\mu s$
2	SIM reset to SIM TX data low	$S_{rst2dat}$	$1.8 \cdot 1 / F_{CKIL}$	1.2	$\mu s$
3	SIM reset to SIM Voltage Enable Low	$S_{rst2ven}$	$2.7 \cdot 1 / F_{CKIL}$	1.8	$\mu s$
4	SIM Presence Detect to SIM reset Low	$S_{pd2rst}$	$0.9 \cdot 1 / F_{CKIL}$	25	ns

**Table 68. 19 x 19 BGA No Connects<sup>1</sup>**

Signal	Ball Location
NC	N7
NC	P7
NC	U21

<sup>1</sup> These contacts are not used and must be floated by the user.

### 5.2.3.2 BGA Signal ID by Ball Grid Location—19 x 19 0.8 mm

**Table 69. 19 x 19 BGA Signal ID by Ball Grid Location**

Signal ID	Ball Location	Signal ID	Ball Location
A0	Y6	CKIL	E21
A1	AC5	CLKO	C20
A10	V15	CLKSS	H17
A11	AB3	COMPARE	A20
A12	AA3	CONTRAST	N21
A13	Y3	CS0	U17
A14	Y15	CS1	Y22
A15	Y14	CS2	Y18
A16	V14	CS3	Y19
A17	Y13	CS4	Y20
A18	V13	CS5	AA21
A19	Y12	CSI_D10	K21
A2	AB5	CSI_D11	K22
A20	V12	CSI_D12	K23
A21	Y11	CSI_D13	L20
A22	V11	CSI_D14	L18
A23	Y10	CSI_D15	L21
A24	Y9	CSI_D4	J20
A25	Y8	CSI_D5	J21
A3	AA5	CSI_D6	L17
A4	Y5	CSI_D7	J22
A5	AC4	CSI_D8	J23
A6	AB4	CSI_D9	K20
A7	AA4	CSI_HSYNC	H22
A8	Y4	CSI_MCLK	H20
A9	AC3	CSI_PIXCLK	H23
ATA_CS0	E1	CSI_VSYNC	H21
ATA_CS1	G4	CSPI1_MISO	N2
ATA_DIOR	E3	CSPI1_MOSI	N1
ATA_DIOW	H6	CSPI1_SCLK	M4
ATA_DMACK	E2	CSPI1_SPI_RDY	M1
ATA_RESET	F3	CSPI1_SS0	M2
BATT_LINE	F6	CSPI1_SS1	N6
BCLK	W20	CSPI1_SS2	M3
BOOT_MODE0	F17	CSPI2_MISO	B4
BOOT_MODE1	C21	CSPI2_MOSI	D5